Headphone driver for digital audio BA3578FS / BA3579FS

The BA3578FS and BA3579FS are headphone drivers with internal an LPF and fixed bass boost circuit for multi-bit D / A converters.

ApplicationsPortable CD players

Features

- Suitable for use in digital audio equipment (line-out output noise voltage: 18μVrms, S / N = 95dB Typ.).
- Internal LPF for multi-bit D / A converters (fc = 34kHz, -12dB / oct. Typ.).
- 4) Internal BB (bass boost) circuit.
- 5) Internal supply current for line-mute transistor.
- 6) No need for output oscillation preventive measures.
- 7) Internal standby switch.

3) Headphone mute function.

Parameter	Symbol	Limits	Unit					
Power supply voltage	AVdd	5.5	V					
Power supply voltage	PVcc	5.5	V					
Power dissipation	Pd	600* ¹	mW					
Operating temperature	Topr	-20~+60	°C					
Storage temperature	Tstg	-55~+125	°C					

• Absolute maximum ratings (Ta = 25° C)

*1 Reduced by 6mW for each increase in Ta of 1°C over 25°C.

Recommended operating conditions

Parameter	Symbol	Limits	Unit	
Power supply voltage	AVdd	3.6	V	
	PVcc	3.6	V	

Recommended operating range

Parameter	Symbol	Limits	Unit
Power supply voltage	AVDD	2.8~5.0	V
	PVcc	2.8~5.0*2	V

*2 In order to use the headphone output to its optimum performance, have the power supply voltage such that $P_{Vec} \ge A_{Vec} = 0.2V$

have the power supply voltage such that $\mathsf{PV}_{\mathsf{CC}} \geqq \mathsf{AV}_{\mathsf{DD}} - 0.3\mathsf{V}$

Block diagram





●Electrical characteristics (Unless otherwise noted, Ta = 25°C, PVcc = AVDD = 3.6V, f = 1kHz, PwSw = ON,

MUTE = OFF, BB = OFF, Line $R_{L1} = 47k\Omega$, headphone $R_{L2} = 32\Omega$, filter = DIN AUDIO, line-out measurements are with $V_{IN}3$ and 4 = 0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
Circuit current	lcc	4.5	7.5	11.5	mA	V _{IN} =0
Power ON voltage	VP	2.0	2.8	_	v	
Power ON pin current	lР	_	60	110	μA	V _{PWSW} =0V
Mute ON voltage	νм	_	0.8	1.4	v	
Mute pin current	Ім	—	110	190	μA	VMUTE=AVDD
Mute output current	Іом	1.0	2.0	_	mA	VMUTE=AVDD
Bass boost OFF voltage	Vв	0.5	0.7	—	v	
〈Line-out〉 (BA3578FS〉						
Voltage gain	Gv1	-2.4	-0.4	1.6	dB	VIN1, 2=0.8Vrms
Voltage gain difference	∆Gv	-2.1	-0.3	1.2	dB	G_{V1} (f=1kHz) $-G_{V1}$ (f=10kHz)
Total harmonic distortion 1	THD ₁	—	0.05	0.2	%	VIN1, 2=0.8Vrms
Maximum output voltage 1	V _{OM1}	0.8	1.1	—	Vrms	THD=0.2%
Output noise voltage 1	V _{NO1}	—	-96	-90	dBV	Rg=0
Channel separation 1	CS1	68	78	_	dB	V _{IN} 1, 2=0.8Vrms, Rg=0
Ripple rejection 1	RR1	37	47	-	dB	VRR=-20dBV, frr=1kHz, Rg=0
〈Line-out〉 (BA3579FS)						
Voltage gain	Gvı	3.6	5.6	7.6	dB	VIN1, 2=0.4Vrms
Voltage gain difference	∆Gv	-2.1	-0.3	1.2	dB	Gv1 (f=1kHz) -Gv1 (f=10kHz)
Total harmonic distortion 1	THD ₁	-	0.05	0.2	%	V _{IN} 1, 2=0.4Vrms
Maximum output voltage 1	Vом1	0.8	1.1	—	Vrms	THD=0.2%
Output noise voltage 1	V _{NO1}	—	-96	-90	dBV	Rg=0
Channel separation 1	CS1	68	78	—	dB	VIN1, 2=0.4Vrms, Rg=0
Ripple rejection 1	RR 1	37	47	—	dB	V _{RR} =-20dBV, f _{RR} =1kHz, Rg=0
\langle Headphone out \rangle						
Voltage gain 2	Gv2	10.2	12.2	14.2	dB	VIN3, 4=-20dBV
Total harmonic distortion 2	THD ₂	—	0.1	0.5	%	VIN3, 4=-20dBV
Rated output	Po	20	32	-	mW	THD=10%
Output noise voltage 2	V _{NO2}	_	-90	-84	dBV	Rg=0
Channel separation 2	CS ₂	59	69	—	dB	VIN3, 4=-20dBV, Rg=0
Channel separation 3	CS₃	11	14	—	dB	VIN3, 4=-20dBV, Rg=0, BB ON
Channel separation 4	CS4	25	35	—	dB	VIN3, 4=-20dBV, Rg=10k Ω
Mute attenuation	АТТм	59	69	—	dB	VIN3, 4=-20dBV, MUTE ON
Bass boost	BB	6.1	9.1	12.1	dB	VIN3, 4=-30dBV, f=100Hz, BB ON
Ripple rejection 2	RR ₂	26	36	_	dB	VRR=-20dBV, frrs=1kHz, Rg=0

ONot designed for radiation resistance.

Measurement circuits

BA3578FS



Units:		
Resistance	: Ω (±1%	5)
Capacitance (film)	: F (±1%	s)
Capacitance (electrolytic)): F (±5%	j,



BA3579FS



Units:	
Resistance :	Ω (±1%)
Capacitance (film) :	F (±1%)
Capacitance (electrolytic):	F (±5%)

Fig.2

Measurement conditions

Parameter	Symbol	SW2	SW4	SW9	SW10	SW13 A	SW13 B	SW14 A	SW14 B	SW16	SW20 A	SW20 B
Circuit current	lcc	2	2	1	1	1	2	1	2	1	1	1
Power ON voltage	VP	Ļ	↓	2	Ļ	Ļ	Ļ	Ļ	ţ	t	2	Ļ
Power ON pin current	IP.	Ļ	Ļ	1	ţ	Ļ	ţ	Ļ	ţ	t	t	t
Mute ON voltage	Vм	Ļ	ţ	ţ	2	ţ	ţ	Ļ	ţ	t	t	ţ
Mute pin current	Ім	Ļ	Ļ	ţ	t	Ļ	ţ	ţ	ţ	t	t	ţ
Mute output current	Іом	Ļ	Ļ	Ļ	1	Ļ	ţ	Ļ	Ļ	ţ	t	ţ
Bass boost OFF voltage	VB	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	t	ţ
〈Line-out〉												
Voltage gain 1	Gv1	1	1	Ļ	Ļ	Ļ	2	Ļ	2	Ļ	Ļ	Ļ
Voltage gain difference	∆Gv	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ
Total harmonic distortion 1	THD ₁	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ
Maximum output voltage 1	Vom1	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ
Output noise voltage 1	V _{NO1}	2	2	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ
Channel separation 1	CS1	1/2	2/1	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ
Ripple rejection 1	RR1	2	2	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	2
$\langle Headphone \ out \rangle$												
Voltage gain 2	Gv2	2	2	ţ	t	ţ	Ļ	Ļ	Ļ	t	t	1
Total harmonic distortion 2	THD₂	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	ţ	Ļ	ţ
Rated output	Po	Ļ	Ļ	ţ	ţ	ţ	ţ	Ļ	ţ	ţ	ţ	ţ
Output noise voltage 2	VNO2	Ļ	Ļ	Ļ	Ļ	Ļ	2	Ļ	2	Ļ	Ļ	Ļ
Channel separation 2	CS ₂	Ļ	Ļ	Ļ	t	Ļ	1/2	Ļ	2/1	t	t	ţ
Channel separation 3	CS₃	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	Ļ	2	t	ţ
Channel separation 4	CS₄	Ļ	Ļ	Ļ	t	2/1	ţ	1/2	Ļ	1	t	ţ
Mute attenuation	ATTм	Ļ	Ļ	ţ	2	1	1	1	1	1	ţ	ţ
Bass boost	BB	Ļ	Ļ	Ļ	ţ	Ļ	Ļ	Ļ	Ļ	2	ţ	ţ
Ripple rejection 2	RR ₂	1	Ļ	Ļ	Ļ	Ļ	2	Ļ	2	1	t	2



ROHM



Units:	
Resistance :	Ω (±5%)
Capacitance (film) :	F (±10%)
Capacitance (electrolytic):	F (±20%)

Fig.4

Circuit operation

(1) By operating the BA3578FS and BA3579FS according to the timing chart shown in Fig. 5, it is possible to suppress generation of "pop" noise in the headphone output.



TP 100msec.

(2) The voltage of the BIAS pin (pin 11) for the BA3578FS and BA3579FS is the voltage divided from the AVDD pin (pin 1). There is no current carrying capacity, so do not use it as an operating point for external circuits.

BA3578FS / BA3579FS



460

